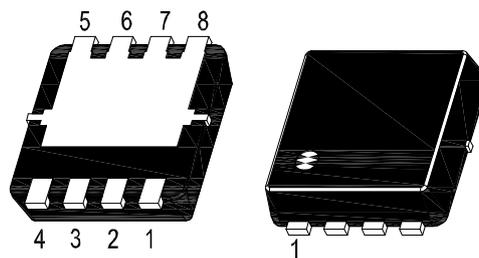
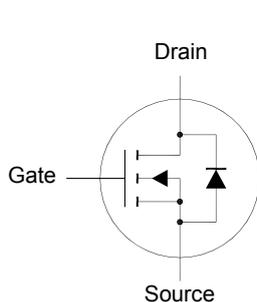


SFTN6412MP

N-Channel Enhancement Mode MOSFET



1. Source 2. Source 3. Source 4. Gate
5. Drain 6. Drain 7. Drain 8. Drain
DFN3030 Plastic Package

Absolute Maximum Ratings

| Parameter | Symbol | Value | Unit |
|--|----------------|---|------------------|
| Drain-Source Voltage | V_{DS} | 65 | V |
| Drain-Gate Voltage | V_{GS} | ± 20 | V |
| Drain Current - Continuous | I_D | 30 19 | A |
| | | $V_{GS} = 10\text{ V}$ $T_C = 25^\circ\text{C}$ $T_C = 100^\circ\text{C}$ | |
| Power Dissipation | P_D | 32 | W |
| | | $T_C = 25^\circ\text{C}$ | |
| Drain Current - Pulsed ¹⁾ | I_{DM} | 60 | A |
| | | $T_C = 25^\circ\text{C}$ | |
| Single Pulse Avalanche Energy ²⁾ | E_{AS} | 121 | mJ |
| Operating Junction and Storage Temperature Range | T_J, T_{stg} | - 55 to + 150 | $^\circ\text{C}$ |

Thermal Characteristics

| Parameter | Symbol | Max. | Unit |
|--|-----------------|------|---------------------------|
| Thermal Resistance Junction to Ambient | $R_{\theta JA}$ | 35 | $^\circ\text{C}/\text{W}$ |
| Thermal Resistance Junction to Case | $R_{\theta JC}$ | 3.9 | $^\circ\text{C}/\text{W}$ |

¹⁾ Repetitive Rating : Pulsed width limited by maximum junction temperature.

²⁾ Limited by T_{jmax} , $V_{GS} = 10\text{ V}$, $L = 0.5\text{ mH}$, $I_{AS} = 22\text{ A}$, $R_G = 25\ \Omega$, Starting $T_J = 25^\circ\text{C}$.

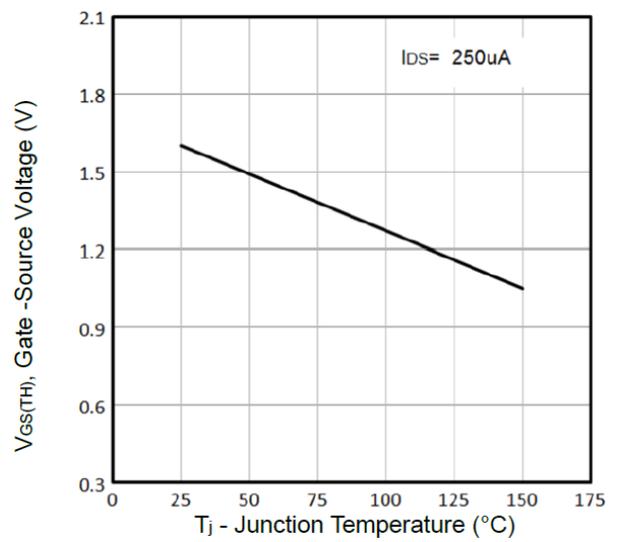
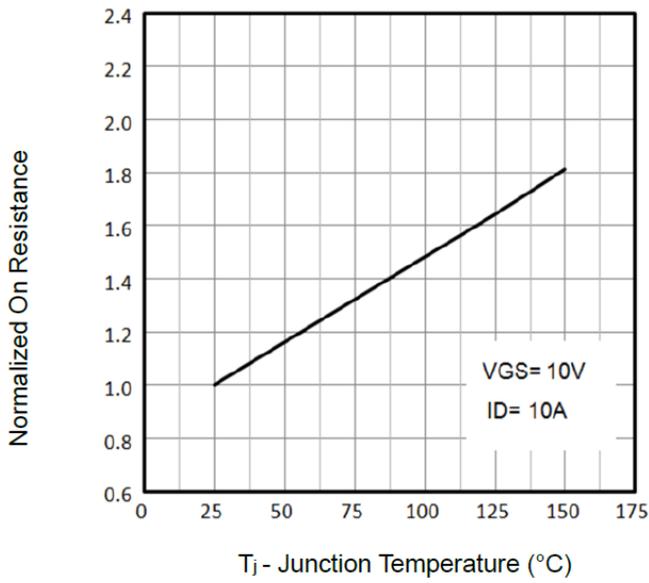
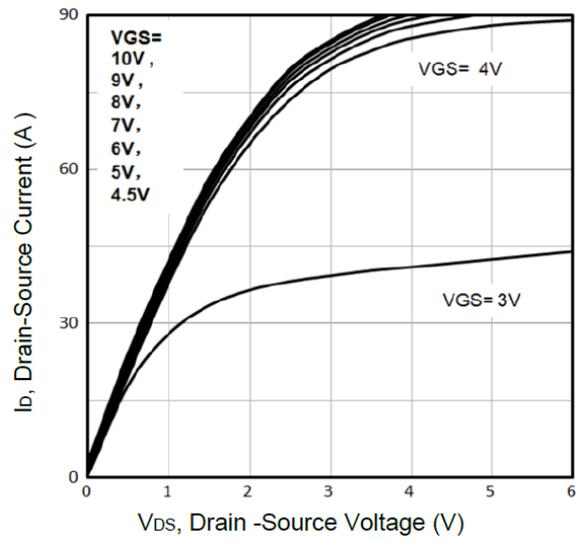
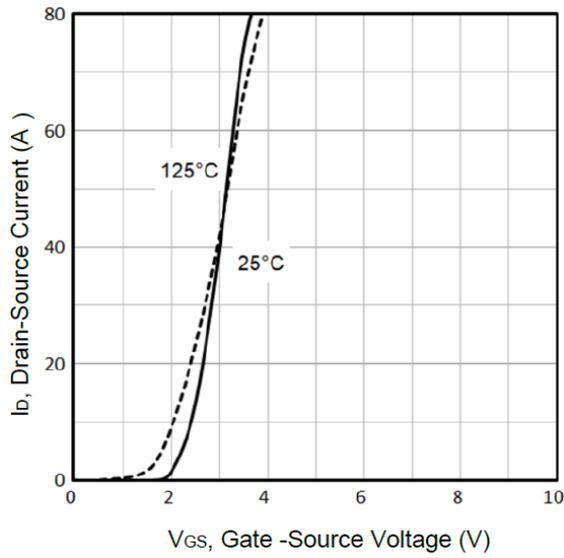
SFTN6412MP

Characteristics at $T_J = 25^\circ\text{C}$ unless otherwise specified

| Parameter | Symbol | Min. | Typ. | Max. | Unit |
|---|--------------|--------|--------|------------|---------------|
| Drain-Source Breakdown Voltage at $I_D = 250\ \mu\text{A}$ | BV_{DSS} | 65 | - | - | V |
| Gate-Source Threshold Voltage at $V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$ | V_{GSth} | 1 | - | 2.5 | V |
| Drain-Source Leakage Current at $V_{DS} = 65\ \text{V}$ at $V_{DS} = 65\ \text{V}, T_J = 125^\circ\text{C}$ | I_{DSS} | - - | - - | 0.1 100 | μA |
| Gate-Source Leakage Current at $V_{GS} = \pm 20\ \text{V}$ | I_{GSS} | - | - | ± 100 | nA |
| Drain-Source On-State Resistance at $V_{GS} = 10\ \text{V}, I_D = 15\ \text{A}$ at $V_{GS} = 4.5\ \text{V}, I_D = 10\ \text{A}$ | $R_{DS(on)}$ | - - | - - | 24 26 | m Ω |
| Input Capacitance at $V_{GS} = 0\ \text{V}, V_{DS} = 30\ \text{V}, f = 1\ \text{MHz}$ | C_{iss} | - | 1240 | - | pF |
| Output Capacitance at $V_{GS} = 0\ \text{V}, V_{DS} = 30\ \text{V}, f = 1\ \text{MHz}$ | C_{oss} | - | 95 | - | pF |
| Reverse Transfer Capacitance at $V_{GS} = 0\ \text{V}, V_{DS} = 30\ \text{V}, f = 1\ \text{MHz}$ | C_{rss} | - | 85 | - | pF |
| Turn-On Delay Time at $V_{GS} = 10\ \text{V}, V_{DD} = 30\ \text{V}, I_D = 5\ \text{A}, R_G = 6.8\ \Omega$ | $t_{d(on)}$ | - | 12 | - | ns |
| Turn-On Rise Time at $V_{GS} = 10\ \text{V}, V_{DD} = 30\ \text{V}, I_D = 5\ \text{A}, R_G = 6.8\ \Omega$ | t_r | - | 8.5 | - | ns |
| Turn-Off Delay Time at $V_{GS} = 10\ \text{V}, V_{DD} = 30\ \text{V}, I_D = 5\ \text{A}, R_G = 6.8\ \Omega$ | t_{off} | - | 42 | - | ns |
| Turn-Off Fall Time at $V_{GS} = 10\ \text{V}, V_{DD} = 30\ \text{V}, I_D = 5\ \text{A}, R_G = 6.8\ \Omega$ | t_f | - | 6 | - | ns |

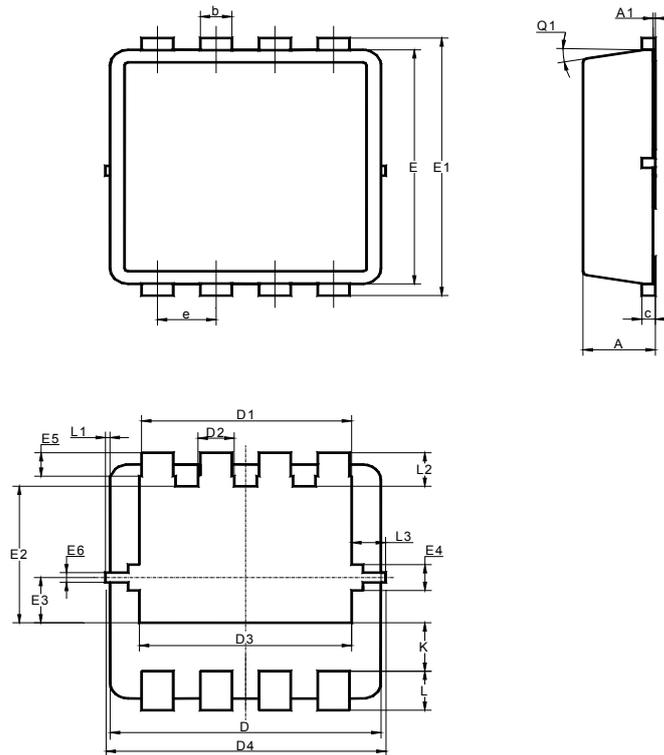
Drain-Source Diode Characteristics and Maximum Ratings

| Parameter | Symbol | Max. | Unit |
|--|----------|------|------|
| Drain-Source Diode Forward Voltage at $V_{GS} = 0\ \text{V}, I_S = 2\ \text{A}$ | V_{SD} | 1.2 | V |



SFTN6412MP

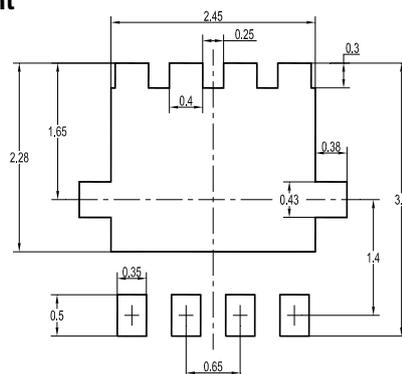
DFN3030 Package Outline Dimensions (Units: mm)



| UNIT | A | A1 | b | c | D | D1 | D2 | D3 | D4 | E | E1 | E2 | E3 |
|------|-----|------|------|------|-----|------|-----|-----|-----|-----|-----|------|------|
| mm | 0.9 | 0.05 | 0.35 | 0.25 | 3.1 | 2.45 | 0.5 | 2.7 | 3.2 | 3.1 | 3.3 | 1.85 | 0.68 |
| | 0.7 | 0 | 0.24 | 0.1 | 2.9 | 2.2 | 0.3 | 2.4 | 3 | 2.9 | 3.1 | 1.65 | 0.48 |

| UNIT | E4 | E5 | E6 | e | K | L | L1 | L2 | L3 | Q1 |
|------|------|-----|-------|-----|------|-----|-----|------|-------|-----|
| mm | 0.43 | 0.4 | 0.25 | 0.7 | 0.72 | 0.5 | 0.1 | 0.53 | 0.475 | 12° |
| | 0.23 | 0.2 | 0.075 | 0.6 | 0.52 | 0.3 | 0 | 0.33 | 0.275 | 0° |

Recommended Soldering Footprint



Packing information

| Package | Tape Width (mm) | Pitch | | Reel Size | | Per Reel Packing Quantity |
|---------|-----------------|---------|---------------|-----------|------|---------------------------|
| | | mm | inch | mm | inch | |
| DFN3030 | 8 | 4 ± 0.1 | 0.157 ± 0.004 | 330 | 13 | 3,000 |

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